

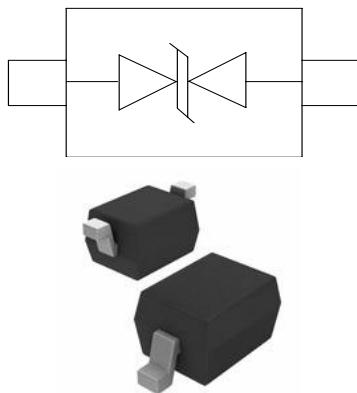
Features

- * 2500W peak pulse power (8/20μs)
- * Low leakage: nA level
- * Low operating voltage: 4.5V
- * Ultra low clamping voltage
- * One power line protects
- * Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: ±30kV
 - Contact discharge: ±30kV
 - IEC61000-4-5 (Lightning) 165A (8/20μs)
- * RoHS Compliant
- * Package: SOD-323
- * Lead Finish: Sn

Description

The ESD56151W04-2/TR is a bi-directional high power TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The ESD56151W04-2/TR complies with the IEC 61000-4-2 (ESD) standard with ±15kV air and ±8kV contact discharge. It is assembled into an ultra-small lead-free SOD-323 package. The small size and high ESD surge protection make ESD56151W04-2/TR an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

Circuit Diagram



Applications

- * Mobile Phones and Accessories
- * Battery Protection
- * USB VBus
- * Power Line Protection
- * Hand Held Portable Applications

Marking Diagram



Transparent top view

48D:Device Marking Code

Ordering Information

Part Number	Packaging	Reel Size
ESD56151W04-2/TR	3000/Tape & Reel	7 inch



Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise specified)

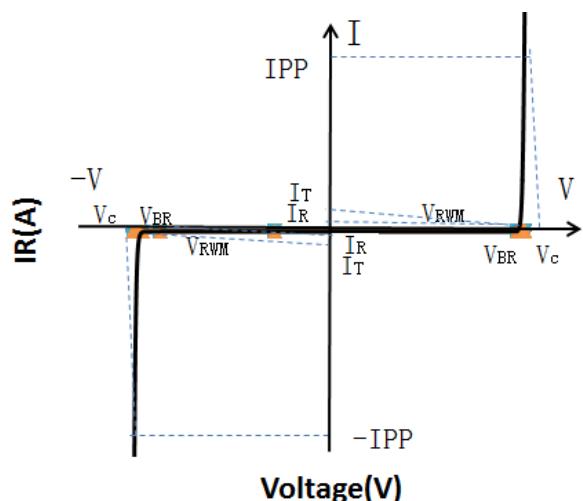
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	2500	W
Peak Pulse Current (8/20μs)	IPP	160	A
ESD per IEC 61000-4-2 (Air)	VESD	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C

Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Working Voltage	V _{RWM}				4.5	V
Breakdown Voltage	V _{BR}	I _T = 1mA	4.8			V
Reverse Leakage Current	I _R	V _{RWM} = 4.5V			1.0	μA
Clamping Voltage	V _C	IPP = 100A (8 x 20μs pulse)		11.0		V
Clamping Voltage	V _C	IPP = 160A (8 x 20μs pulse)			14.5	V
Junction Capacitance	C _J	VR = 0V, f = 1MHz	330	400		pF

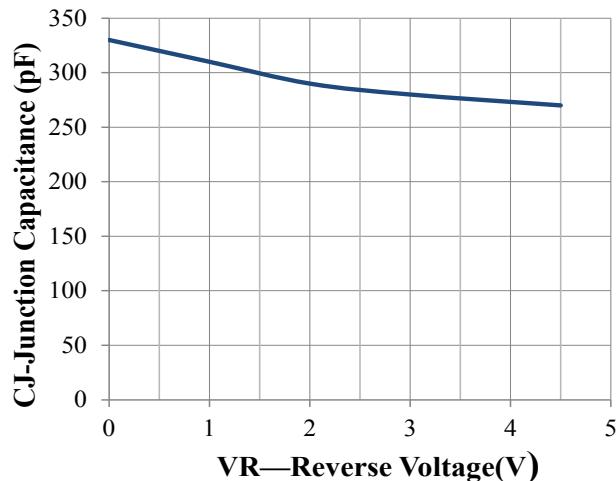
Portion Electronics Parameter

Symbol	Parameter
I _T	Test Current
IPP	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @I _c

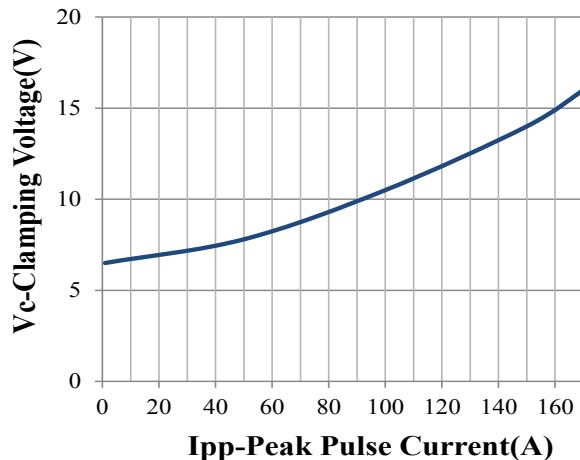




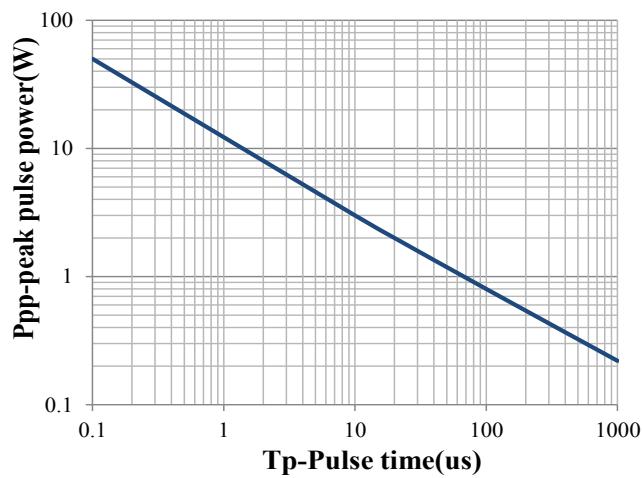
Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise Specified)



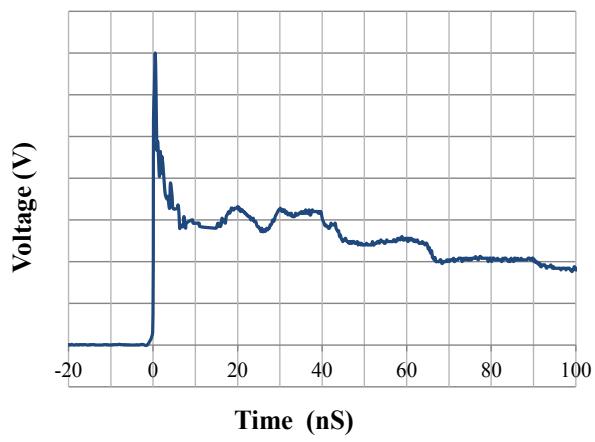
Junction Capacitance vs. Reverse Voltage



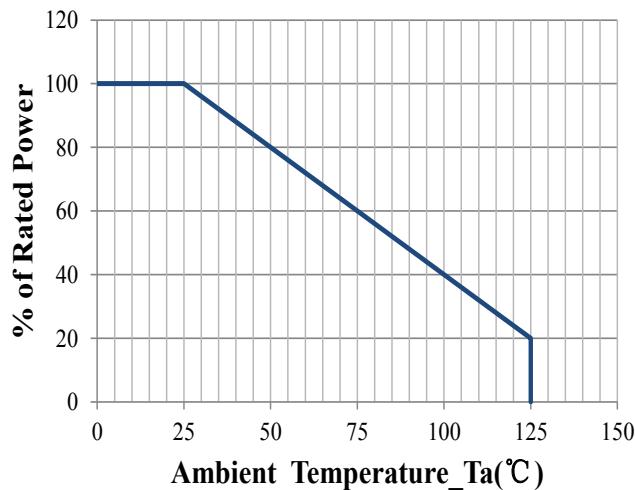
Clamping Voltage vs. Peak Pulse Current



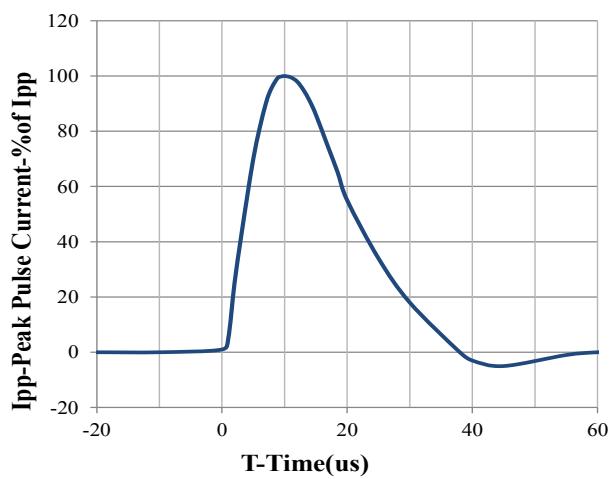
Peak Pulse Power vs. Pulse Time



IEC61000-4-2 Pulse Waveform



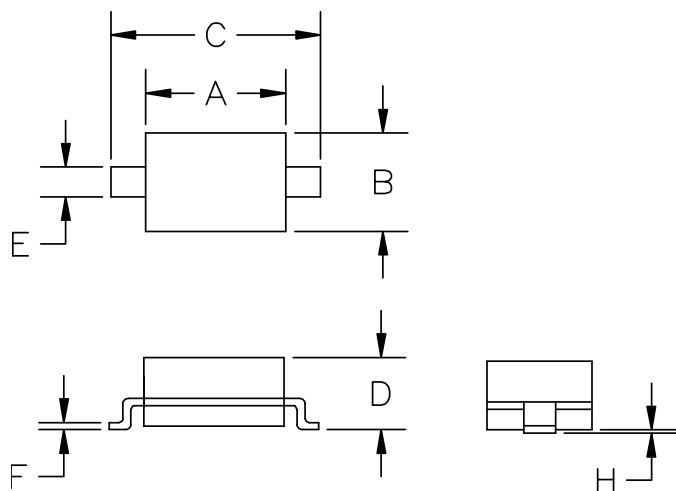
Power Derating Curve



8 X 20us Pulse Waveform

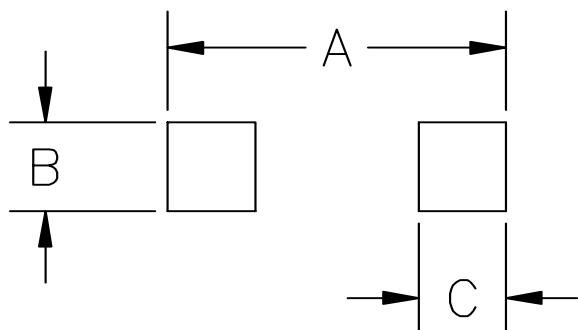


SOD-323 Package Outline Drawing



SYM	DIMENSIONS			
	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.50	1.80	0.060	0.071
B	1.20	1.40	0.045	0.054
C	2.30	2.70	0.090	0.107
D	-	1.10	-	0.043
E	0.30	0.40	0.012	0.016
F	0.10	0.25	0.004	0.010
H	-	0.10	-	0.004

Suggested Land Pattern



SYM	DIMENSIONS	
	MILLIMETERS	
	INCHES	INCHES
A	3.15	0.120
B	0.80	0.031
C	0.80	0.031